TOSHIBA Infrared LED GaAlAs Infrared Emitter

# **TLN238(F)**

Lead(Pb)-Free Space-Optical-Transmission Opto-Electronic Switches Printers, Fax Machines Home Electric Equipment

• High radiant intensity: 70 mW/sr (typ.) at IF = 50 mA

Half-angle value:  $\theta 1/2 = \pm 18^{\circ}$  (typ.)

High-speed data transmission purposes

## Absolute Maximum Ratings (Ta = 25°C)

Characteristics	Symbol	Rating	Unit	
Forward current	l <sub>F</sub>	100	mA	
Pulse forward current	I <sub>FP</sub>	1000 (Note 1)	mA	
Power dissipation	$P_{D}$	200	mW	
Reverse voltage	$V_{R}$	4	V	
Operating temperature range	T <sub>opr</sub>	-25~85	°C	
Storage temperature range	T <sub>stg</sub>	-30~100	°C	
Soldering temperature (5 s), (Note 2)	T <sub>sol</sub>	260	°C	

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in

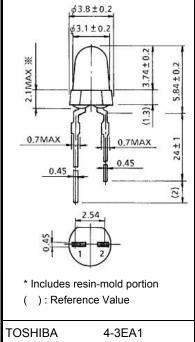
temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings. Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Note 1: f = 100 kHz, duty = 1%

Note 2: Soldering must be performed 2 mm from the bottom of the package body.

5.84±0.2

Unit: mm



Weight: 0.14 g (typ.)

#### **Pin Connection**

1. Anode 1 ○ → ○ 2

2. Cathode



## **Optical and Electrical Characteristics (Ta = 25°C)**

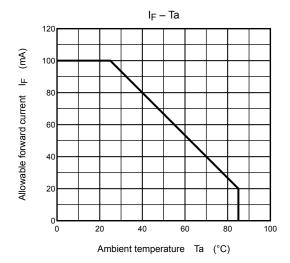
Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Forward voltage	V <sub>F</sub>	I <sub>F</sub> = 100 mA	_	1.6	2.0	V
Reverse current	I <sub>R</sub>	V <sub>R</sub> = 4 V	_	_	60	μА
Radiant intensity	ΙE	I <sub>F</sub> = 50 mA	40	70	_	mW/sr
Cut-off frequency	f <sub>C</sub>	$I_F = 50 \text{ mA} + 5 \text{ mA}_{P-P}$ (Note 3)	_	15	_	MHz
Peak emission wavelength	λР	I <sub>F</sub> = 50 mA	_	870	_	nm
Half-angle value	$\theta \frac{1}{2}$	I <sub>F</sub> = 50 mA	_	±18		0

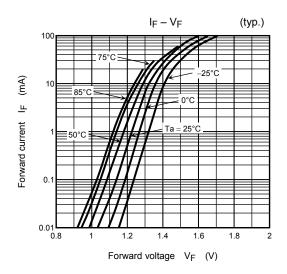
Note 3: This is the frequency when modulation light power decreases by 3 dB from 1 MHz.

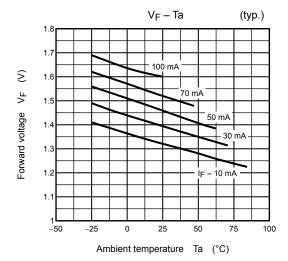
### **Handling Precautions**

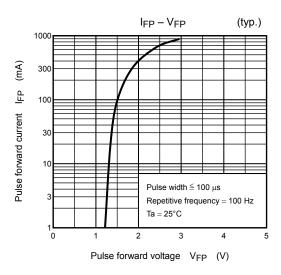
- Soldering must be performed under the stopper.
- When forming the leads, bend each lead at least 5 mm from the package body. Soldering must be performed after the leads have been formed.
- The radiant intensity decreases over time due to current flowing in the infrared LED. When designing circuits, take into account the change in radiant intensity over time.

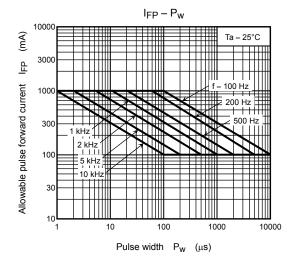
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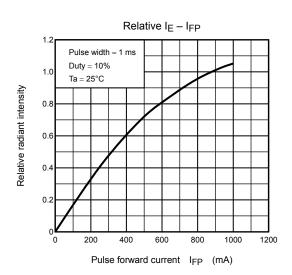




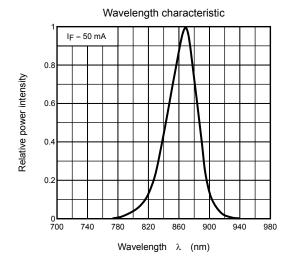


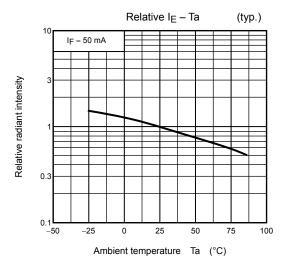


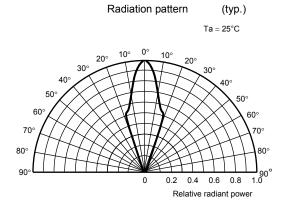




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